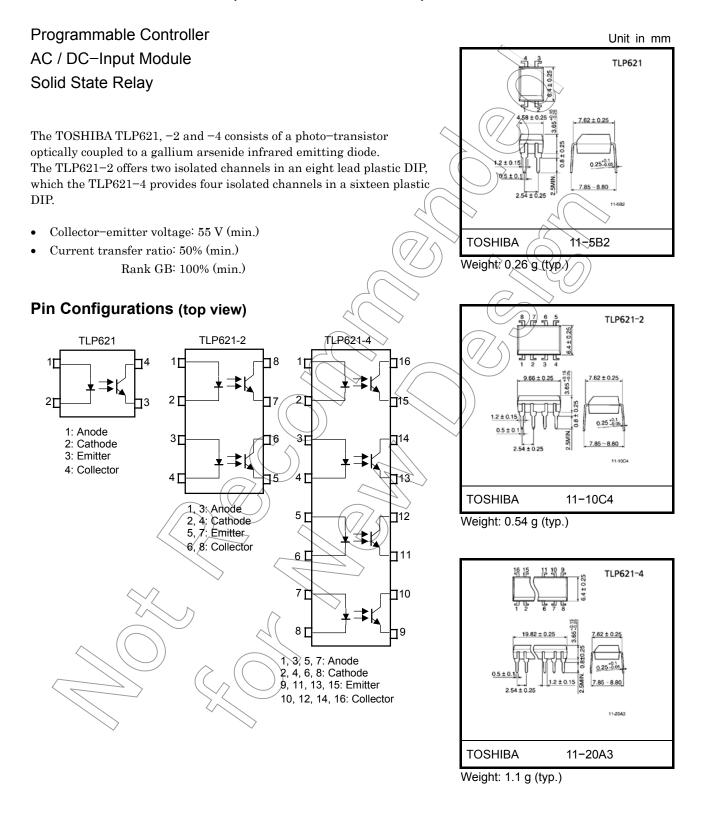
TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP621,TLP621-2,TLP621-4



2007-10-01

• Current Transfer Ratio

Туре	Classi– fication *1	Current Transfer Ratio (%) (I_C / I_F) $I_F = 5mA$, $V_{CE} = 5V$, $Ta = 25^{\circ}C$		Marking Of Classification
		Min.	Max.	
	(None)	50	600	Blank, Y, Y [■] , G, G [■] , B, B [■] , GB
	Rank Y	50	150	Y, Y**
TLP621	Rank GR	100	300	G, G "
	Rank BL	200	600	B, B*
	Rank GB	100	600	G, G [*] , B, B [*] , GB
TLP621-2	(None)	50	600	Blank, GR, BL, GB
TLP621-4	Rank GB	100	600	GR, BL, GB

*1: Ex. rank GB: TLP621 (GB)

(Note) Application type name for certification test, please use standard product type name, i.e.

2

TLP621 (GB): TLP621

TLP621-2 (GB): TLP621-2

	Made In Japan		Made In Thailand
UL recognized	E67349	*2	E152349 *2
BSI approved	6508, 7445	*3	6505, 7445 *3
SEMKO approved	9735090 / 01	*4	

*2 UL1577

*3 BS EN60065: 2002, BS EN60950-1:/2002

*4 EN60950 (approved is TLP621 only)



• Option (D4) type

VDE approved: DIN EN 60747-5-2, certificate no. 40009302

Maximum operating insulation voltage: 890 V_{PK} Highest permissible over voltage: 8000 V_{PK}

(Note) When a EN 60747-5-2 approved type is needed, please designate the "Option (D4)"





Absolute Maximum Ratings (Ta = 25°C)

			Ra	ting	
	Characteristic	Symbol	TLP621	TLP621-2 TLP621-4	Unit
	Forward current	lF	60	50	mA
	Forward current derating	ΔI _F /°C	−0.7 (Ta > 39°C)	−0.5 (Ta = 25°C)	mA /°C
	Pulse forward current	I _{FP}	1 (100µs pu	lse, 100pps)	Α
LED	Power dissipation	PD	100	70 (mW
	Power dissipation derating	ΔP _D /°C	-1.0	-0.7	mW /°C
	Reverse voltage	V _R			V
	Junction temperature	Tj	12	25	°C
	Collector-emitter voltage	V _{CEO}	5	V	
	Emitter-collector voltage	V _{ECO}			V
<u>_</u>	Collector current	IC	50		mA
Detector	Collector power dissipation (1 circuit)	PC	150	100	mW
	Collector power dissipation derating (1 circuit, Ta ≥ 25°C)	ΔP _C /°C	1.5	-1.0	mW/1°C
	Junction temperature	Tj	12	25	>°C
Stor	rage temperature range	T _{stg}	-55r	-125) °C
Оре	erating temperature range	T _{opr} (-55r	~100	°C
Lead soldering temperature		T _{sol}	260 ((10,s)	°C
Total package power dissipation		PT	250	150	mW
Total package power dissipation derating (Ta ≥ 25°C)		ΔP _T /°C	-2.5	-1.5	mW /°C
Isola	ation voltage (Note 1)	BVs	5000 (AC, 1mi	n., R.H.≤ 60%)	V _{rms}

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Device considered a two terminal: LED side pins shorted together, and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{CC}	_	5	24	V
Forward current	ΙF	_	16	20	mA
Collector current	IC	_	1	10	mA
Operating temperature	T _{opr}	-25		85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.



Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5 V	_	_	10	μA
	Capacitance	C _T	V = 0, f = 1 MHz		30	_	pF
	Collector–emitter breakdown voltage	V _(BR) CEO	I _C = 0.5 mA	55	7	_	V
Detector	Emitter-collector breakdown voltage	V _(BR) ECO	I _E = 0.1 mA		7_	ı	V
Dete	Collector dark current	I _{CEO}	V _{CE} = 24 V	\mathcal{I}	10	100	nA
	Collector dark current		V _{CE} = 24 V, Ta = 85°C	_	2	50	μΑ
	Capacitance (collector to emitter)	C _{CE}	V = 0, f = 1 MHz	_	10	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

		// / / \ \			/	
Characteristic	Symbol	Test Condition	MIn.	Typ	Max.	Unit
Current transfer ratio	I _C / I _F	I _F = 5 mA, V _{CE} = 5 V	50		600	%
Current transfer fatto	1C / 1F	Rank GB	100	_	600	70
Saturated CTP	I _C / I _F (sat)	IE = 1 mA, VCE = 0.4 V		60		%
Saturated CTR		Rank GB	30	_	_	70
	4(IC = 2,4 mA, I _F = 8 mA	_	_	0.4	
Collector–emitter saturation voltage	V _{CE} (sat)	IC = 0.2 mA, IF = 1 mA		0.2	_	V
		Rank GB		_	0.4	

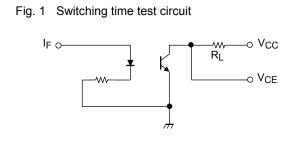
Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance (input to output)	Cs	V _S = 0, f ≠ 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V	1×10 ¹²	10 ¹⁴	_	Ω
		AC, 1 minute	5000	_	_	V
Isolation voltage	BVS	AC, 1 second, in oil	_	10000	_	V _{rms}
		DC, 1 minute, in oil	_	10000	_	V _{dc}



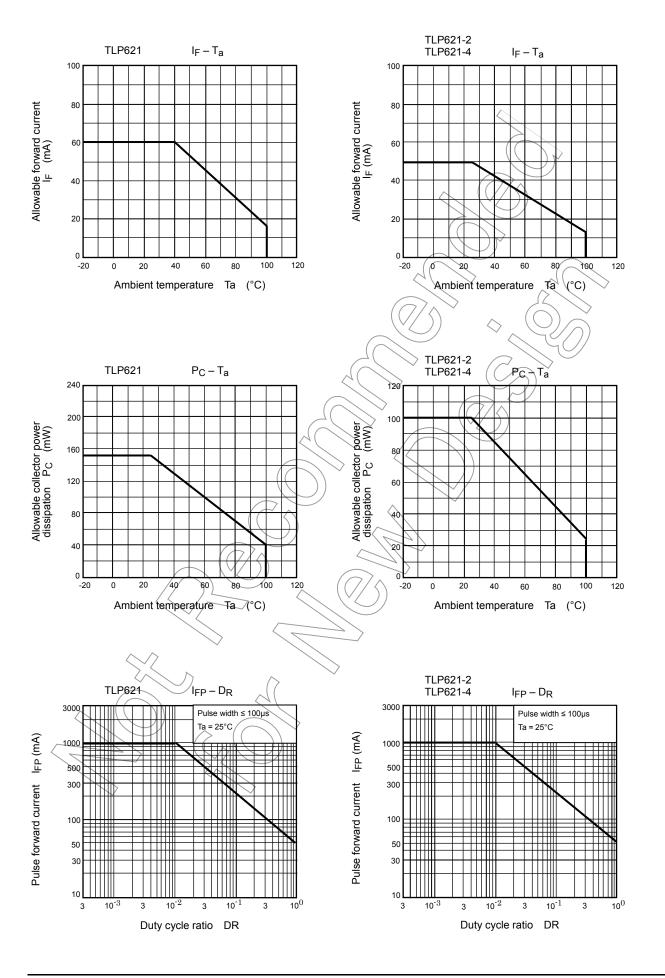
Switching Characteristics (Ta = 25°C)

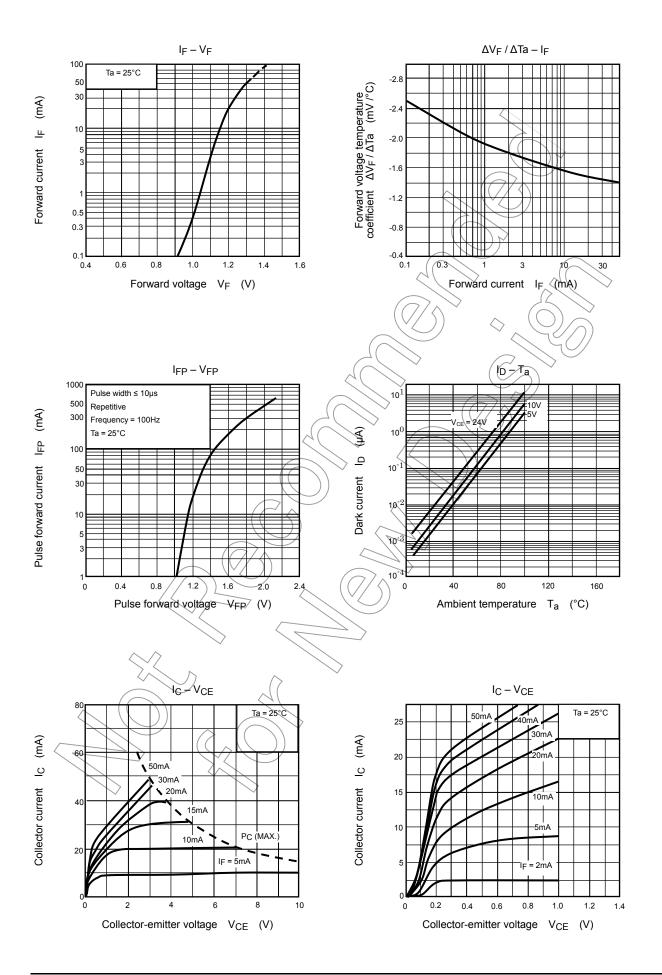
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Rise time	t _r		_	2	_	
Fall time	t _f	V_{CC} = 10 V, I_C = 2 mA R_L = 100 Ω	_	3	_	
Turn-on time	t _{on}			3	_	μs
Turn-off time	t _{off}			3	_	
Turn-on time	t _{ON}		(F) >2	_	
Storage time	t _S	$R_L = 1.9 \text{ k}\Omega \text{ (Fig.1)}$ $V_{CC} = 5 \text{ V, I}_F = 16 \text{ mA}$	\nearrow	15	_	μs
Turn-off time	toff		$\bigcirc)$	25	_	

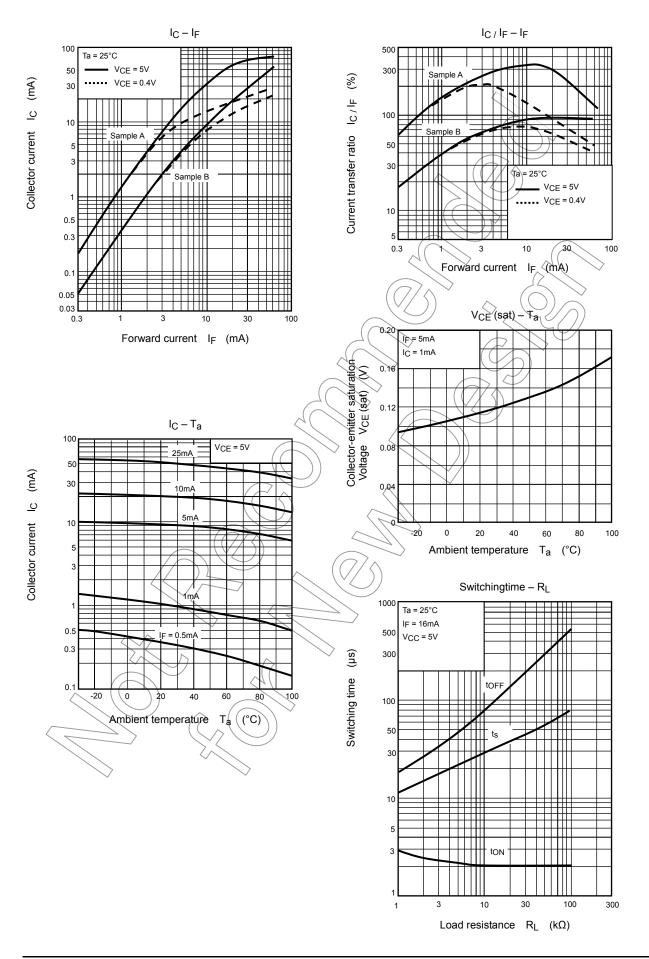




6







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